

# NCE6007AS

### NCE N-Channel Enhancement Mode Power MOSFET

### **Description**

The NCE6007AS uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

#### **General Features**

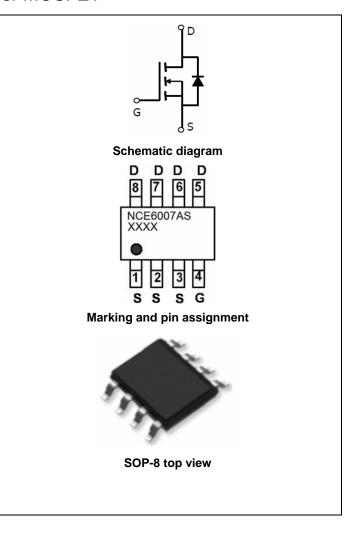
V<sub>DS</sub> =60V,I<sub>D</sub> =7A

 $R_{DS(ON)} < 30 m\Omega$  @  $V_{GS} = 10V$  (Typ:  $22 m\Omega$ )  $R_{DS(ON)} < 35 m\Omega$  @  $V_{GS} = 4.5V$  (Typ:  $27 m\Omega$ )

- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Low gate to drain charge to reduce switching losses

### **Application**

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply



#### Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE6007AS	NCE6007AS	SOP-8	Ø330mm	12mm	2500 units

### Absolute Maximum Ratings (T<sub>A</sub>=25℃unless otherwise noted)

<u> </u>	<u> </u>		
Parameter	Symbol	Limit	Unit
Drain-Source Voltage	VDS	60	V
Gate-Source Voltage	V <sub>G</sub> s	±20	V
Drain Current-Continuous	I <sub>D</sub>	7	А
Drain Current-Continuous(T <sub>C</sub> =100°C)	I <sub>D</sub> (100℃)	5	Α
Pulsed Drain Current	I <sub>DM</sub>	40	А
Maximum Power Dissipation	P <sub>D</sub>	2.1	W
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 150	$^{\circ}$ C

### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ hetaJA}$	60	°C/W

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# Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

Parameter	Symbol Condition		Min	Тур	Max	Unit	
Off Characteristics							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	=0V I <sub>D</sub> =250μA 60		-	V	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V,V <sub>GS</sub> =0V	60V,V <sub>GS</sub> =0V -		1	μA	
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA	
On Characteristics (Note 3)							
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS},I_{D}=250\mu A$	1.0	1.4	2.0	V	
Danier Course On Otata Basistana	Б	V <sub>GS</sub> =10V, I <sub>D</sub> =7A			30	mΩ	
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =6A		27	35	mΩ	
Forward Transconductance	<b>g</b> FS	$V_{DS}$ =5 $V$ , $I_{D}$ =7 $A$		20	-	S	
Dynamic Characteristics (Note4)	<u> </u>		l.		<u> </u>		
Input Capacitance	C <sub>lss</sub>	V 05VV 0V		1920		PF	
Output Capacitance	Coss	$V_{DS}$ =25V, $V_{GS}$ =0V, F=1.0MHz		155		PF	
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHZ		116		PF	
Switching Characteristics (Note 4)					•		
Turn-on Delay Time	t <sub>d(on)</sub>		-	8	-	nS	
Turn-on Rise Time	t <sub>r</sub>	$V_{DS}$ =30V, $R_L$ =4.7 $\Omega$	-	5	-	nS	
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10 $V$ , $R_{GEN}$ =3 $\Omega$	-	29	-	nS	
Turn-Off Fall Time	t <sub>f</sub>		-	6	-	nS	
Total Gate Charge	Qg	V -20VI -7A	-	50	-	nC	
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =30V, $I_{D}$ =7A, $V_{GS}$ =10V	-	8	-	nC	
Gate-Drain Charge	$Q_{gd}$	VGS-10V	-	16	-	nC	
Drain-Source Diode Characteristic	cs				•		
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =7A	V <sub>GS</sub> =0V,I <sub>S</sub> =7A -		1.2	V	
Diode Forward Current (Note 2)	Is		-		7	Α	
Reverse Recovery Time	t <sub>rr</sub>	TJ = 25°C, I <sub>F</sub> =7A	-	35	-	nS	
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	43	-	nC	
Forward Turn-On Time	t <sub>on</sub>	Intrinsic turn-on time is negligible (turn-o	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

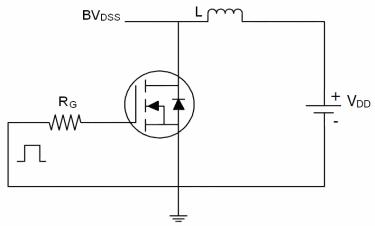
### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production

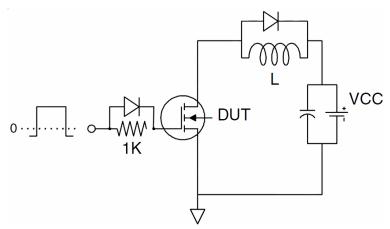


# **Test Circuit**

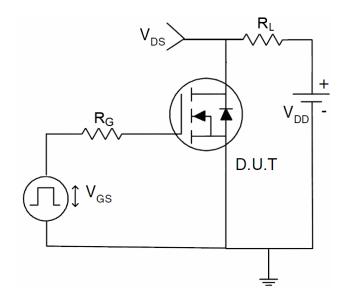
# 1) E<sub>AS</sub> test Circuits



## 2) Gate charge test Circuit

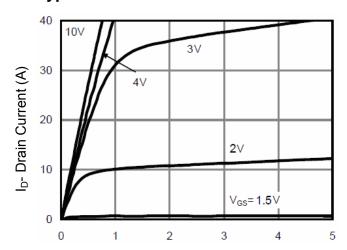


### 3) Switch Time Test Circuit



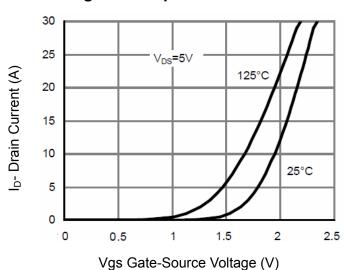


## **Typical Electrical and Thermal Characteristics (Curves)**



Vds Drain-Source Voltage (V)





**Figure 2 Transfer Characteristics** 

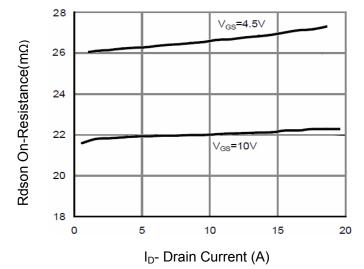


Figure 3 Rdson- Drain Current

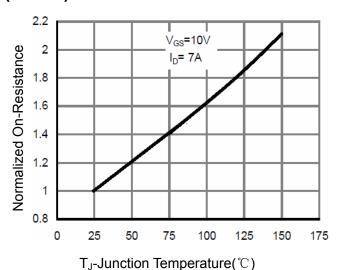


Figure 4 Rdson-JunctionTemperature

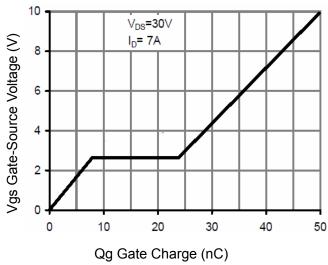


Figure 5 Gate Charge

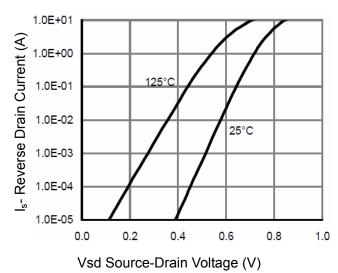


Figure 6 Source- Drain Diode Forward

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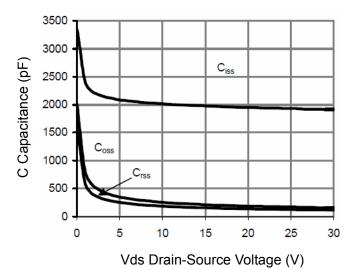


Figure 7 Capacitance vs Vds

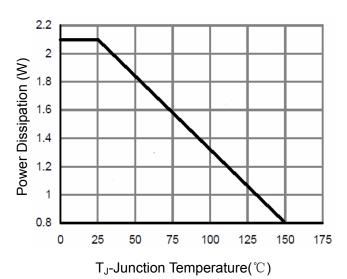
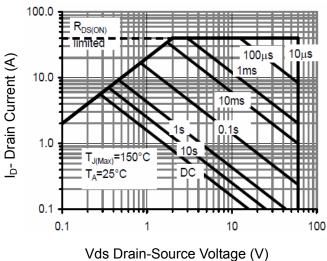


Figure 9 Power De-rating



**Figure 8 Safe Operation Area** 

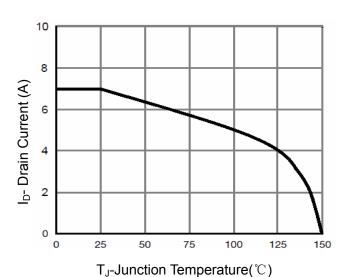


Figure 10 Current De-rating

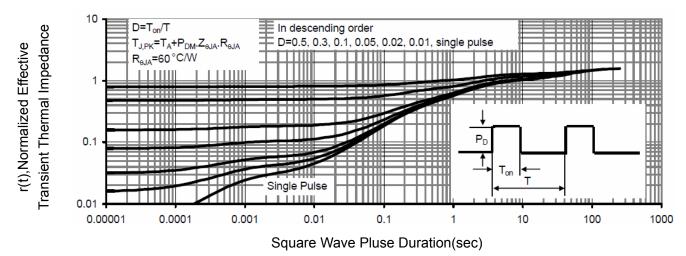
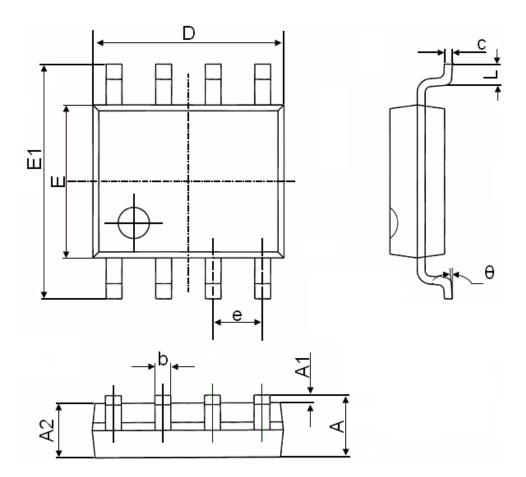


Figure 11 Normalized Maximum Transient Thermal Impedance

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# **SOP-8 Package Information**



Symbol	Dimensions	n Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
С	0.170	0.250	0.006	0.010	
D	4.700	5.100	0.185	0.200	
E	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
е	1.270	1.270(BSC)		(BSC)	
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	



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